STEALTH[™] Dual Diode 30 A, 600 V

ISL9K1560G3

Description

The ISL9K1560G3 is a STEALTH dual diode optimized for low loss performance in high frequency hard switched applications. The STEALTH family exhibits low reverse recovery current (I_{RR}) and exceptionally soft recovery under typical operating conditions.

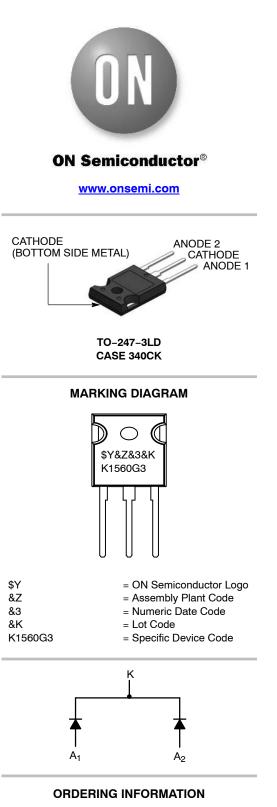
This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RR} and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Features

- Stealth Recovery $t_{rr} = 29.4 \text{ ns} (@ I_F = 15 \text{ A})$
- Max Forward Voltage, $V_F = 2.2 V (@ T_C = 25^{\circ}C)$
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode



See detailed ordering and shipping information on page 2 of this data sheet.

DEVICE MAXIMUM RATINGS (per leg) ($T_C = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Ratings	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	600	V	
Working Peak Reverse Voltage	V _{RWM}	600	V	
DC Blocking Voltage	V _R	600	V	
Average Rectified Forward Current (T _C = 145°C) Total Device Current (Both Legs)	I _{F(AV)}	15 30	A A	
Repetitive Peak Surge Current (20 kHz Square Wave)	I _{FRM}	30	Α	
Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60 Hz)	I _{FSM}	200	Α	
Power Dissipation	PD	150	W	
Avalanche Energy (1 A, 40 mH)	E _{AVL}	20	mJ	
Operating and Storage Temperature Range	T _{J,} T _{STG}	–55 to +175	°C	
Maximum Temperature for Soldering Leads at 0.063 in (1.6 mm) from Case for 10 s Package Body for 10 s, See Techbrief TB334	T _L T _{PKG}	300 260	°C °C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Packing Method	Tape Width	Quantity
ISL9K1560G3	K1560G3	TO-247-3L	Tube	N/A	30

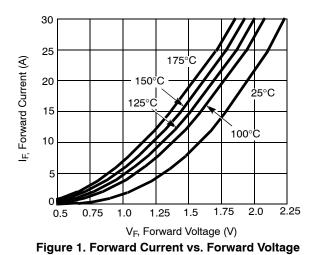
THERMAL CHARACTERISTICS

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta JC}$		-	-	1.0	°C/W
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	TO-247	-	-	30	°C/W

ELECTRICAL CHARACTERISTICS (per leg) ($T_C = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
OFF STATE CHARACTERISTICS	;						
Instantaneous Reverse Current	I _R	V _R = 600 V	$T_C = 25^{\circ}C$	-	-	100	μA
			T _C = 125°C	-	-	1.0	mA
ON STATE CHARACTERISTICs							
Instantaneous Forward Voltage	VF	I _F = 15 A	$T_{C} = 25^{\circ}C$	-	1.8	2.2	V
			T _C = 125°C	-	1.65	2.0	V
DYNAMIC CHARACTERISTICS							
Junction Capacitance	CJ	V _R = 10 V, I _F = 0 A		-	62	-	pF
SWITCHING CHARACTERISTIC	S						
Reverse Recovery Time	t _{rr}	$I_F = 1 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	25	30	ns
		I _F = 15 A, dl/dt = 100 A/µs, V _R = 30 V		-	35	40	ns
Reverse Recovery Time	t _{rr}	$ I_F = 15 \text{ A}, \\ dI_F/dt = 200 \text{ A}/\mu\text{s}, \\ V_R = 390 \text{ V}, \\ T_C = 25^\circ\text{C} $		-	29.4	-	ns
Reverse Recovery Current	۱ _{rr}			-	3.5	-	Α
Reverse Recovered Charge	Q _{rr}			-	57	-	nC
Reverse Recovery Time	t _{rr}	$ I_F = 15 \text{ A}, \\ dI_F/dt = 200 \text{ A}/\mu\text{s}, \\ V_R = 390 \text{ V}, \\ T_C = 125^\circ\text{C} $		-	90	-	ns
Softness Factor (t _b / _{ta})	S			-	2.0	-	
Reverse Recovery Current	I _{RR}			-	5.0	-	Α
Reverse Recovered Charge	Q _{RR}			-	275	-	nC
Reverse Recovery Time	t _{rr}	$ I_F = 15 \text{ A}, \\ dI_F/dt = 800 \text{ A}/\mu\text{s}, \\ V_R = 390 \text{ V}, \\ T_C = 125^\circ\text{C} $		-	52	-	ns
Softness Factor (t _b / _{ta})	S			-	1.36	-	
Reverse Recovery Current	I _{RR}			-	13.5	-	Α
Reverse Recovered Charge	Q _{RR}			-	390	-	nC
Maximum di/dt during t _b	dl _{M/} dt			-	800	-	A/μs

TYPICAL PERFORMANCE CURVES



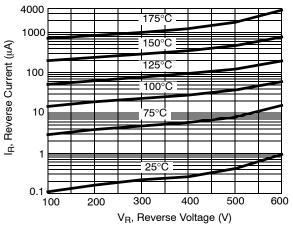


Figure 2. Reverse Current vs. Reverse Voltage

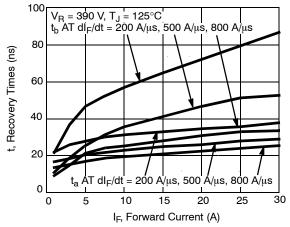
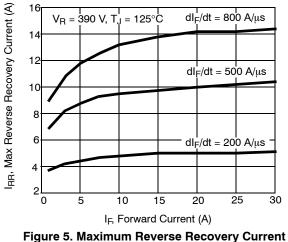


Figure 3. t_a and t_b Curves vs. Forward Current



vs. Forward Current

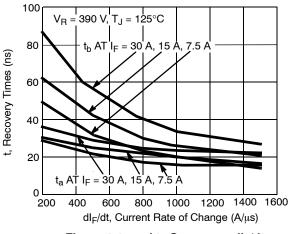
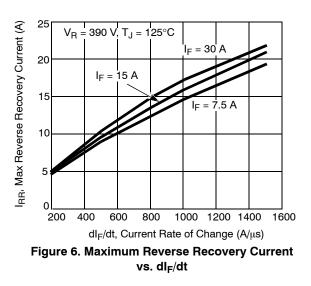


Figure 4. t_a and t_b Curves vs. $dI_{\mbox{\scriptsize F}}/dt$



TYPICAL PERFORMANCE CURVES (continued)

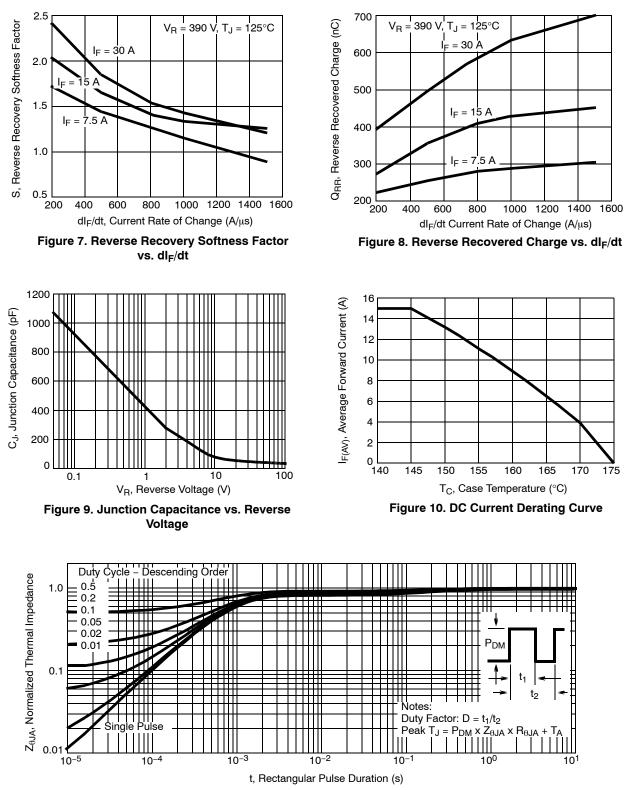
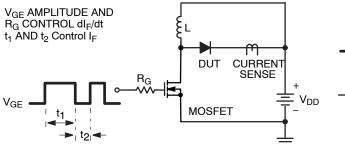
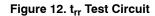


Figure 11. Normalized Maximum Transient Thermal Impedance

TEST CIRCUIT AND WAVEFORMS





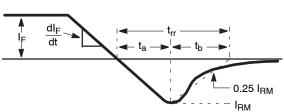


Figure 13. t_{rr} Waveforms and Definitions

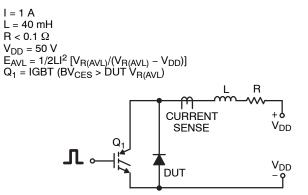


Figure 14. Avalanche Energy Test Circuit

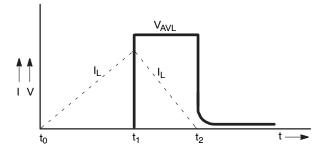
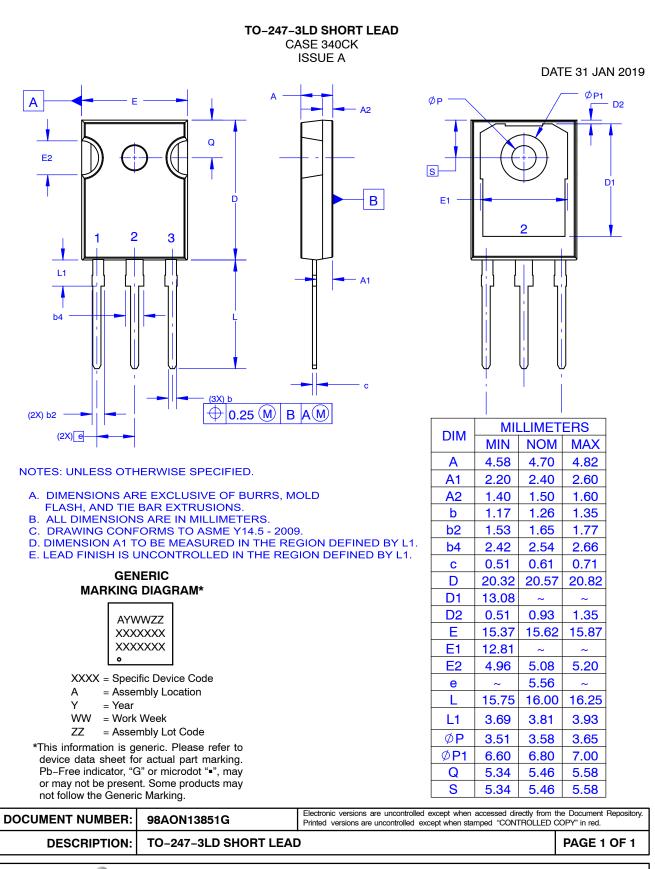


Figure 15. Avalanche Current and Voltage Waveforms

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